

1.5V Drive Pch MOSFET

RT1A060AP

● Structure

Silicon P-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) Low voltage drive (1.5V drive).
- 3) Small surface mount package (TSST8).

● Application

Switching

● Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
RT1A060AP		○

● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V_{DSS}	-12	V	
Gate-source voltage	V_{GSS}	0 to -8	V	
Drain current	Continuous	I_D	±6	A
	Pulsed	I_{DP} *1	±18	A
Source current (Body Diode)	Continuous	I_S	-1	A
	Pulsed	I_{SP} *1	-18	A
Power dissipation	P_D *2	1.25	W	
Channel temperature	T_{ch}	150	°C	
Range of storage temperature	T_{stg}	-55 to +150	°C	

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

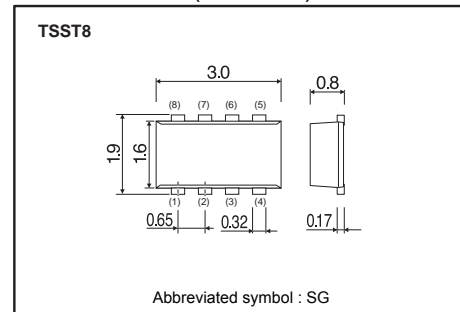
*2 Mounted on a ceramic board.

● Thermal resistance

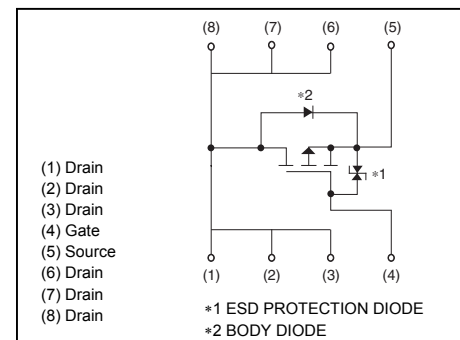
Parameter	Symbol	Limits	Unit
Channel to Ambient	$R_{th}(ch-a)^*$	100	°C / W

*Mounted on a ceramic board.

● Dimensions (Unit : mm)



● Inner circuit



● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	-10	μA	$V_{GS}=-8\text{V}, V_{DS}=0\text{V}$
Drain-source breakdown voltage	$V_{(BR)DSS}$	-12	-	-	V	$I_D=-1\text{mA}, V_{GS}=0\text{V}$
Zero gate voltage drain current	I_{DSS}	-	-	-10	μA	$V_{DS}=-12\text{V}, V_{GS}=0\text{V}$
Gate threshold voltage	$V_{GS(th)}$	-0.3	-	-1.0	V	$V_{DS}=-6\text{V}, I_D=-1\text{mA}$
Static drain-source on-state resistance	$R_{DS(on)}$ *	-	14	19	m Ω	$I_D=-6\text{A}, V_{GS}=-4.5\text{V}$
		-	17	24		$I_D=-3\text{A}, V_{GS}=-2.5\text{V}$
		-	22	33		$I_D=-3\text{A}, V_{GS}=-1.8\text{V}$
		-	27	54		$I_D=-1.2\text{A}, V_{GS}=-1.5\text{V}$
Forward transfer admittance	$ Y_{fs} $ *	9	-	-	S	$V_{DS}=-6\text{V}, I_D=-6\text{A}$
Input capacitance	C_{iss}	-	7800	-	pF	$V_{DS}=-6\text{V}$
Output capacitance	C_{oss}	-	900	-	pF	$V_{GS}=0\text{V}$
Reverse transfer capacitance	C_{rss}	-	850	-	pF	$f=1\text{MHz}$
Turn-on delay time	$t_{d(on)}$ *	-	25	-	ns	$V_{DD}=-6\text{V}, I_D=-3\text{A}$
Rise time	t_r *	-	100	-	ns	$V_{GS}=-4.5\text{V}$
Turn-off delay time	$t_{d(off)}$ *	-	580	-	ns	$R_L=2\Omega, R_G=10\Omega$
Fall time	t_f *	-	260	-	ns	
Total gate charge	Q_g *	-	80	-	nC	$V_{DD}=-6\text{V}, I_D=-6\text{A}$
Gate-source charge	Q_{gs} *	-	12	-	nC	$V_{GS}=-4.5\text{V}$
Gate-drain charge	Q_{gd} *	-	13	-	nC	

*Pulsed

● Body diode characteristics (Source-Drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V_{SD} *	-	-	-1.2	V	$I_S=-6\text{A}, V_{GS}=0\text{V}$

*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics (I)

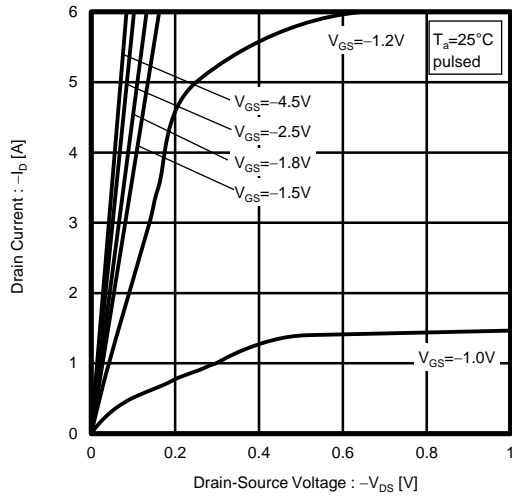


Fig.2 Typical Output Characteristics (II)

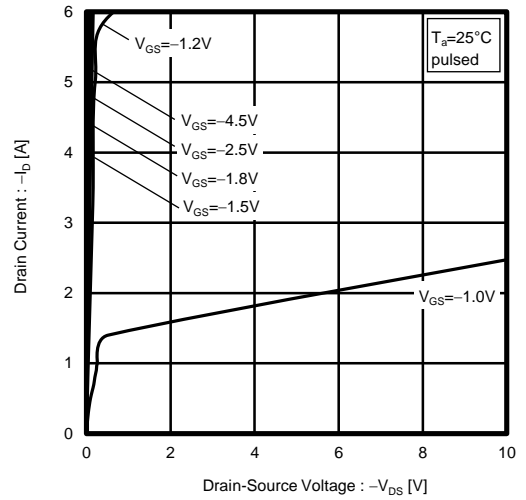


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

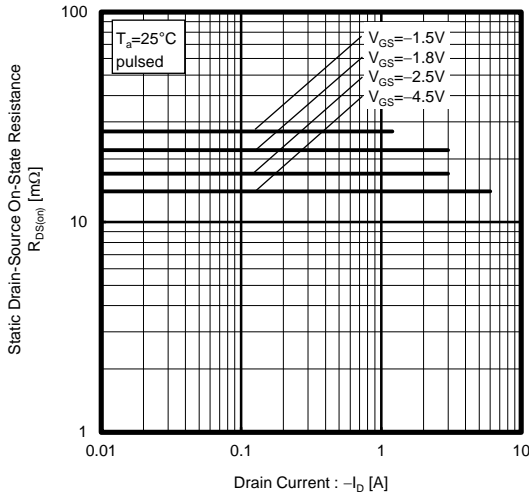


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

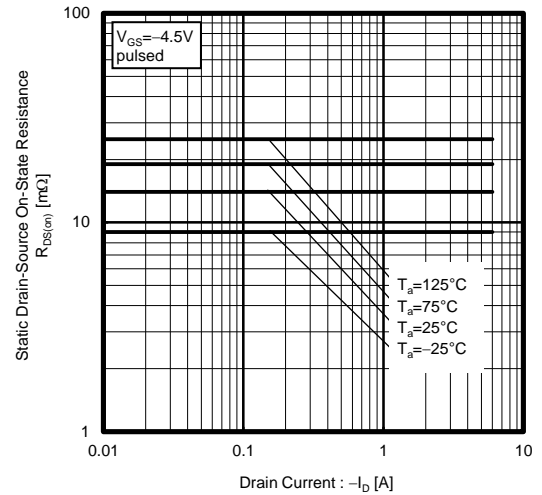


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

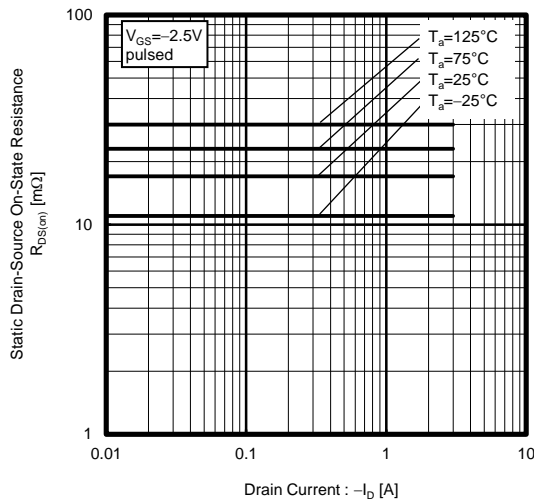


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current

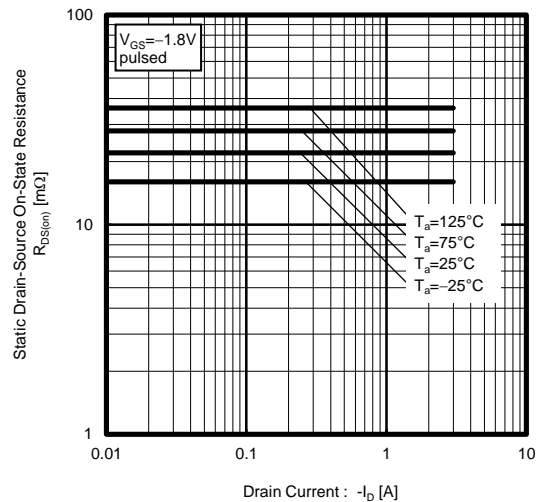


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current

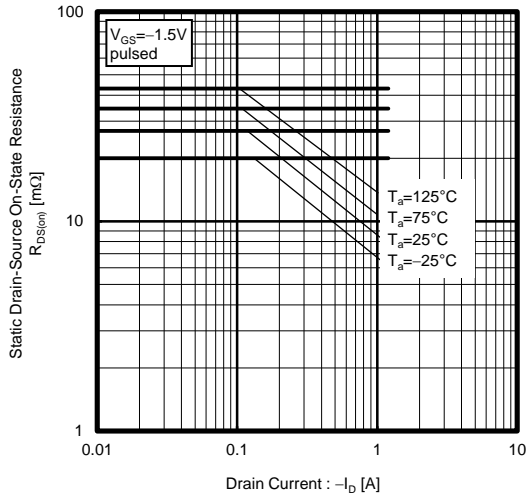


Fig.8 Forward Transfer Admittance vs. Drain Current

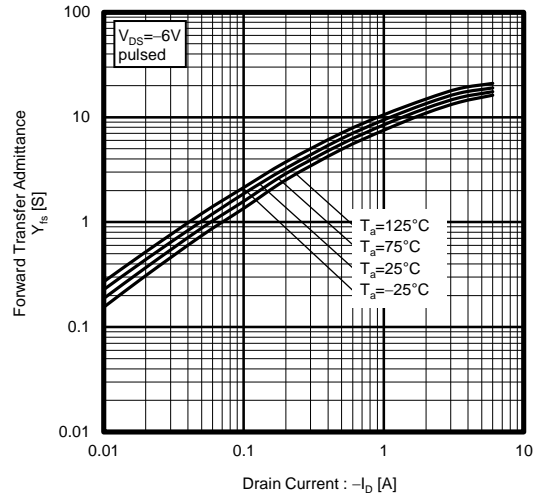


Fig.9 Typical Transfer Characteristics

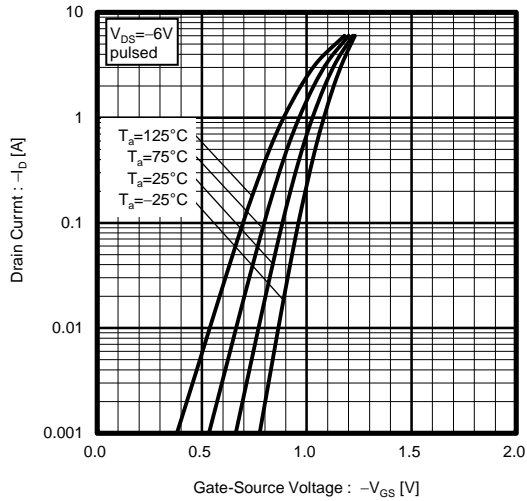


Fig.10 Source Current vs. Source-Drain Voltage

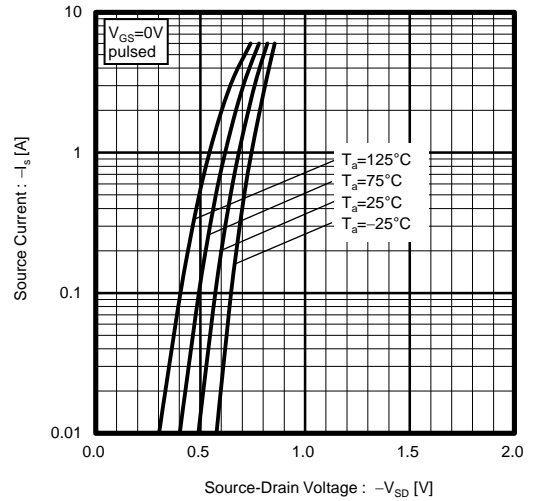


Fig.11 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

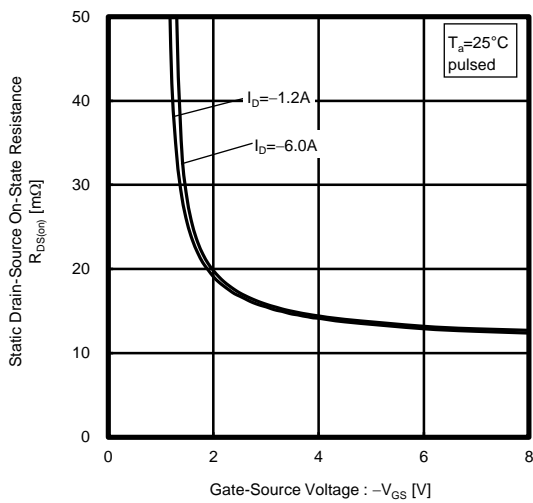


Fig.12 Switching Characteristics

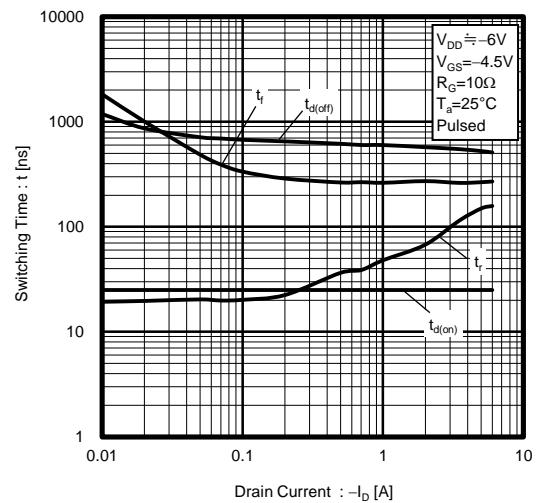


Fig.13 Dynamic Input Characteristics

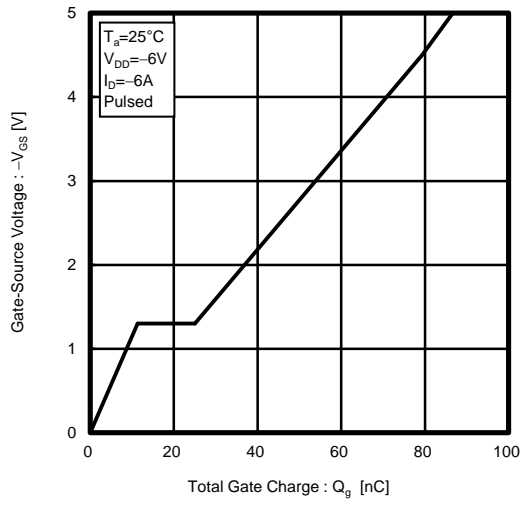


Fig.14 Typical Capacitance vs. Drain-Source Voltage

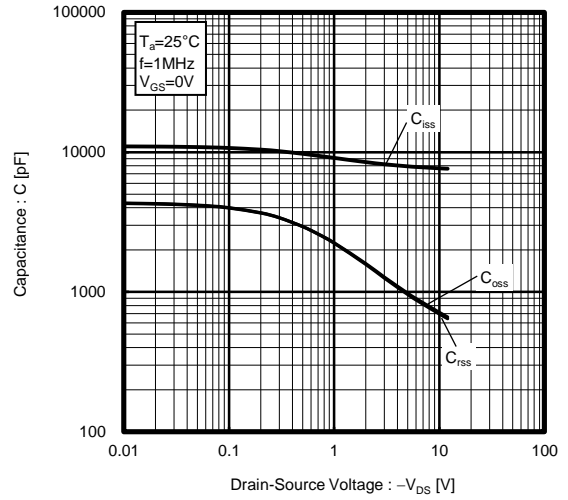


Fig.15 Normalized Transient Thermal Resistance v.s. Pulse Width

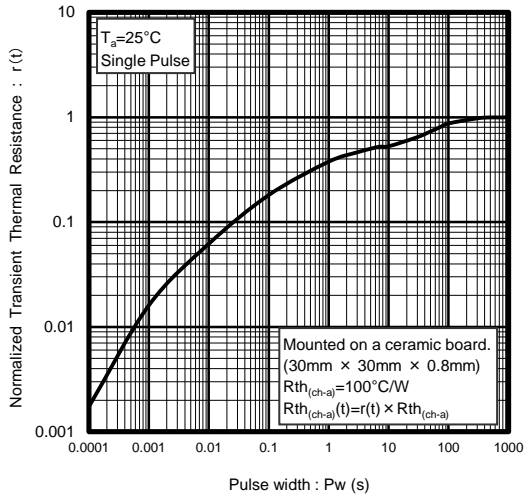
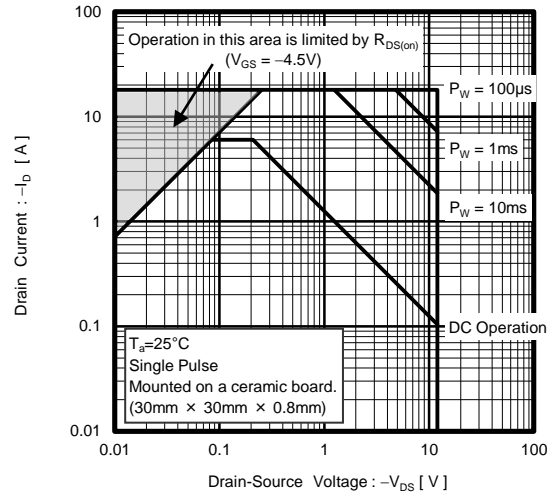


Fig.16 Maximum Safe Operating Area



● Measurement circuits

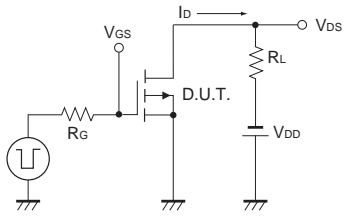


Fig.1-1 Switching Time Measurement Circuit

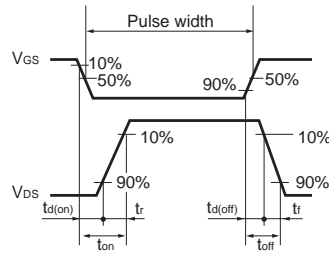


Fig.1-2 Switching Waveforms

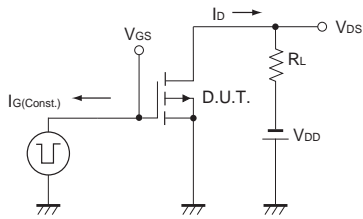


Fig.2-1 Gate Charge Measurement Circuit

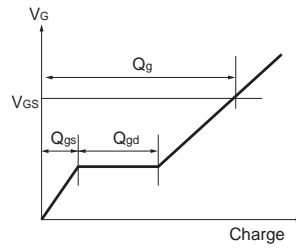


Fig.2-2 Gate Charge Waveform

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